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FAST RECOVERY DIODE**ARF694****FOR IGBT, IEGT, GCT APPLICATIONS****SNUBBERLESS OPERATION****LOW LOSSES SOFT RECOVERY**

Repetitive voltage up to

6000 V

Mean forward current

645 A

Surge current

10 kA**TARGET SPECIFICATION**

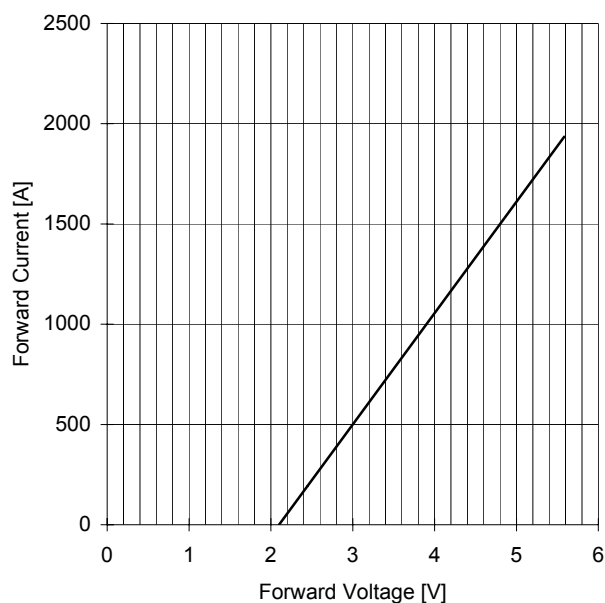
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| Symbol | Characteristic | Conditions | T _j [°C] | Value | Unit |
|--|-------------------------------------|--|------------------------|-------------|-------|
| BLOCKING | | | | | |
| V _{RRM} | Repetitive peak reverse voltage | | 120 | 6000 | V |
| V _{RSM} | Non-repetitive peak reverse voltage | | 120 | 6100 | V |
| I _{RRM} | Repetitive peak reverse current | V=VRRM | 120 | | mA |
| V _{DC LINK} | Permanent DC voltage | | 120 | 3200 | V |
| CONDUCTING | | | | | |
| I _{F (AV)} | Mean forward current | 180° sin ,50 Hz, Th=55°C, double side cooled | | 645 | A |
| I _{F (AV)} | Mean forward current | 180° square, 50 Hz, Th=55°C, double side cooled | | 675 | A |
| I _{FSM} | Surge forward current | Sine wave, 10 ms | 120 | 10 | kA |
| I ² t | I ² t | reapplied reverse voltage up to 50% VRSM | | 500 x1E3 | A²s |
| V _{FM} | Forward voltage | Forward current = 1570 A | 25 | 4.8 | V |
| V _{F(TO)} | Threshold voltage | | 120 | 2.10 | V |
| r _F | Forward slope resistance | | 120 | 1.80 | mohm |
| SWITCHING | | | | | |
| Q _{rr} | Reverse recovery charge | I _F = 1000 A di/dt= 250 A/μs VR = 100 V | 120 | | μC |
| I _{rr} | Peak reverse recovery current | | 120 | | A |
| t _{rr} | Reverse recovery time | I _F = 1000 A di/dt= 500 A/μs VR = V | 120 | | μs |
| Q _{rr} | Reverse recovery charge | | | 2000 | μC |
| I _{rr} | Peak reverse recovery current | | | 1150 | A |
| s | Softness (s-factor), min | | | | |
| E _{OFF} | Turn off energy dissipation | | | | J |
| V _{FR} | Peak forward recovery | di/dt= 500 A/μs | 125 | | V |
| MOUNTING | | | | | |
| R _{th(j-h)} | Thermal impedance | Junction to heatsink, double side cooled | | 21 | °C/kW |
| R _{th(c-h)} | Thermal impedance | Case to heatsink, double side cooled | | 3 | °C/kW |
| T _j | Operating junction temperature | | | -30 / 120 | °C |
| F | Mounting force | | | 22.0 / 24.5 | kN |
| | Mass | | | 520 | g |
| ORDERING INFORMATION : ARF694 S 60 standard specification <input type="checkbox"/> <input type="checkbox"/> VRRM/100 | | | | | |

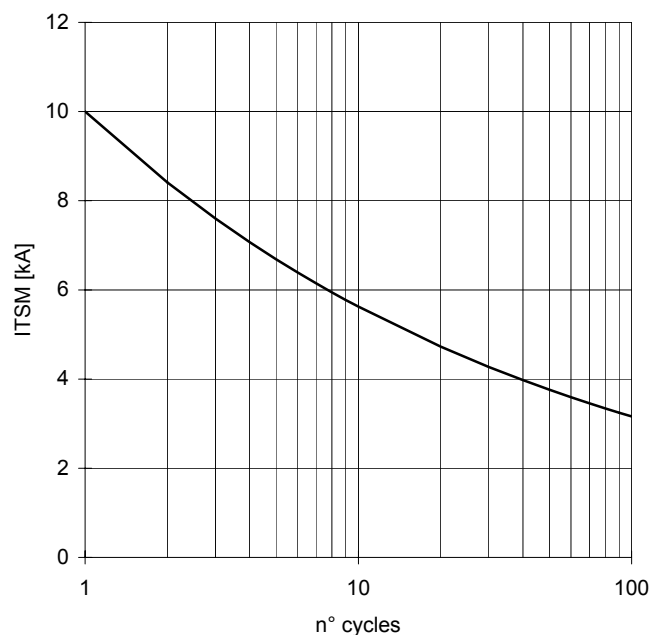
ARF694 FAST RECOVERY DIODE

TARGET SPECIFICATION mar 03 - ISSUE : 2

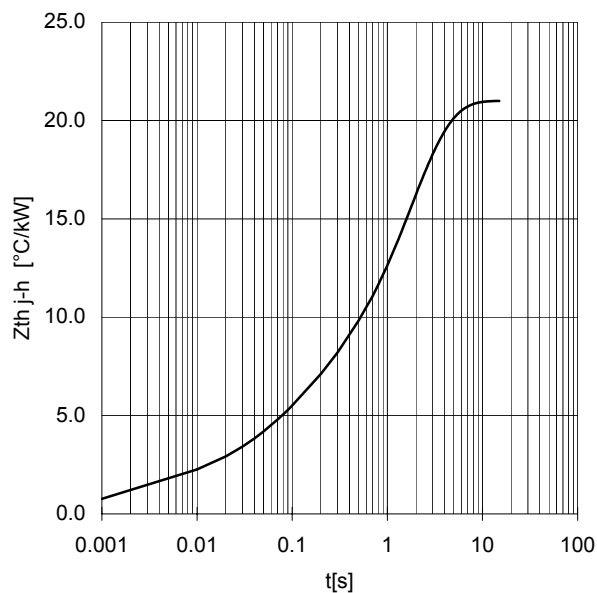
FORWARD CHARACTERISTIC
 $T_j = 120^\circ\text{C}$



SURGE CHARACTERISTIC
 $T_j = 120^\circ\text{C}$



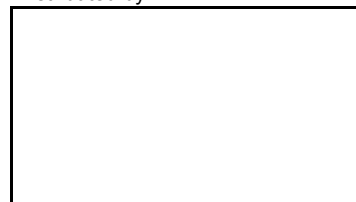
TRANSIENT THERMAL IMPEDANCE
DOUBLE SIDE COOLED



Dimensions
in mm



Distributed by



All the characteristics given in this data sheet are guaranteed only with uniform clamping force, cleaned and lubricated heatsink, surfaces with flatness < 0.03 mm and roughness < 2 μm .

In the interest of product improvement POSEICO SpA reserves the right to change any data given in this data sheet at any time without previous notice.

If not stated otherwise the maximum value of ratings (symbols over shaded background) and characteristics is reported.